





DMP3025LK3



#### **30V P-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub>	I <sub>D</sub> T <sub>A</sub> = 25°C		
-30V	25mΩ @ V <sub>GS</sub> = -10V	-16.1A		
	41mΩ @ V <sub>GS</sub> = -4.5V	-12.5A		

### **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

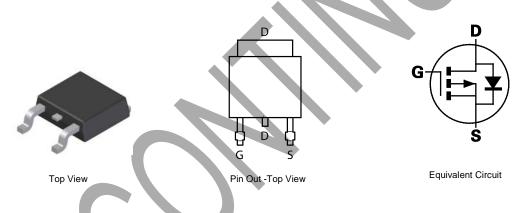
- Backlighting
- DC-DC Converters
- Power management functions

#### **Features and Benefits**

- Low on-resistance
- Fast switching speed
- "Green" component and RoHS compliant (Note 1)

#### **Mechanical Data**

- Case: TO252-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Below
- Ordering Information: See Below
- Weight: 0.33 grams (approximate)

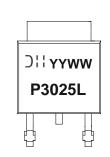


#### Ordering Information (Note 1)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMP3025LK3-13	P3025L	13	16	2,500

Note: 1. Diodes, Inc. defines "Green" products as those which are Eu RoHS compliant and contain no halogens or antimony compounds; further information about Diodes Inc.'s "Green" Policy can be found on our website. For packaging details, go to our website.

## Marking Information



>\\\ = Manufacturer's Marking P3025L = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 09 = 2009) WW = Week (01-52)





#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic			Symbol	Value	Unit	
Drain-Source voltage			V <sub>DSS</sub>	-30	V	
Gate-Source voltage			V <sub>GS</sub>	±20	V	
		(Note 3)		-16.1		
Continuous Drain current	$V_{GS} = 10V$	T <sub>A</sub> =70°C (Note 3)	I <sub>D</sub>	-12.9	А	
		(Note 2)		-10.6		
Pulsed Drain current	V <sub>GS</sub> = 10V	(Note 4)	I <sub>DM</sub>	-41.9	А	
Continuous Source current (	Body diode)	(Note 3)	Is	-12.6	A	
Pulsed Source current (Body diode) (Note 4)		I <sub>SM</sub>	-41.9	А		

#### Thermal Characteristics @TA = 25°C unless otherwise specified

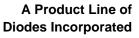
Characteristic	Symbol	Value	Unit	
	(Note 2)		4.3 34.5	
Power dissipation Linear derating factor	(Note 3)	Po	10.0 80.0	W mW/°C
	(Note 5)		2.15 17.2	
	(Note 2)		29.0	
Thermal Resistance, Junction to Ambient	(Note 3)	R <sub>0</sub> JA	12.5	0000
	(Note 5)		58.0	°C/W
Thermal Resistance, Junction to Lead	(Note 6)	$R_{ heta JL}$	1.02	
Operating and storage temperature range		TJ, TSTG	-55 to 150	۵°

2. For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition. Notes:

3. Same as note 2, except the device is pulsed with D = 0.02 and pulse width 300 µs. The pulse current is limited by the maximum junction temperature. 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is

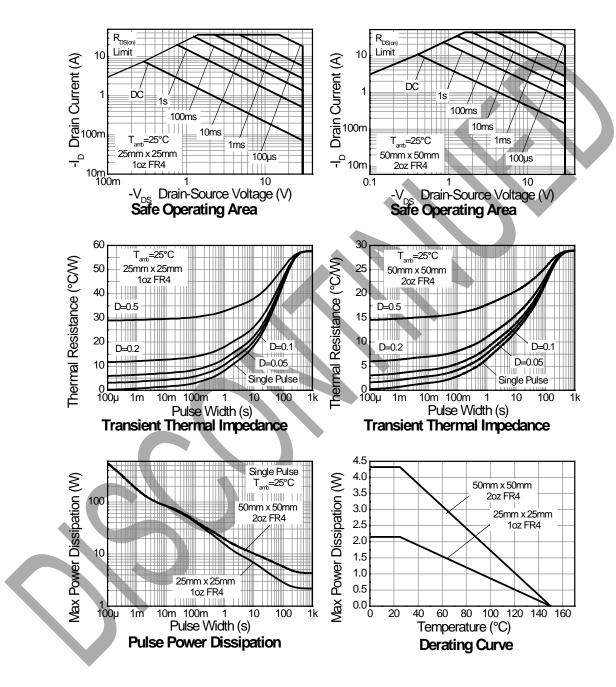
- measured when operating in a steady-state condition.
- 6. Thermal resistance from junction to solder-point (at the end of the drain lead).







#### **Thermal Characteristics**







DMP3025LK3

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS			•		•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	V	I <sub>D</sub> = -250μA, V <sub>GS</sub> = 0V		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-0.5	μA	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V		
Gate-Source Leakage	I <sub>GSS</sub>			±100	nA	$V_{GS}$ = ±20V, $V_{DS}$ = 0V		
ON CHARACTERISTICS								
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.0	_	-3.0	V	$I_{D}$ = -250 $\mu$ A, $V_{DS}$ = $V_{GS}$		
Static Drain-Source On-Resistance (Note 7)	Rea (au)			0.025	•	V <sub>GS</sub> = -10V, I <sub>D</sub> = -7.1A		
	R <sub>DS (ON)</sub>			0.041		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -5.5A		
Forward Transconductance (Notes 7 & 8)	<b>g</b> fs	_	18.6		S	V <sub>DS</sub> = -15V, I <sub>D</sub> = -7.1A		
Diode Forward Voltage (Note 7)	V <sub>SD</sub>	_	-0.80	-1.2	V	I <sub>S</sub> = -1.7A, V <sub>GS</sub> = 0V		
Reverse recovery time (Note 8)	t <sub>rr</sub>		16.2	_	ns			
Reverse recovery charge (Note 8)	Q <sub>rr</sub>	_	10	_	nC	–1 <sub>S</sub> = -2.2A, di/dt= 100A/μs		
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance	C <sub>iss</sub>	_	1678	—	pF			
Output Capacitance	C <sub>oss</sub>		303		pF	−V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V – f= 1MHz		
Reverse Transfer Capacitance	C <sub>rss</sub>		178	1	pF			
Total Gate Charge	Qg		16.5		nC	V <sub>GS</sub> = -4.5V		
Total Gate Charge	Qg		31.6		nC	V <sub>DS</sub> = -15V,		
Gate-Source Charge	Q <sub>gs</sub>		4.3		nC	V <sub>GS</sub> = -10V I <sub>D</sub> = -7.1A		
Gate-Drain Charge	Q <sub>gd</sub>	-	6.2		nC			
Turn-On Delay Time (Note 9)	t <sub>D(on)</sub>	_	3.5		ns			
Turn-On Rise Time (Note 9)	tr	—	4.9	_	ns	V <sub>DD</sub> = -15V, V <sub>GS</sub> = -10V		
Turn-Off Delay Time (Note 9)	t <sub>D(off)</sub>	-	44		ns	$I_D$ = -1A, $R_G \cong 6.0\Omega$		
Turn-Off Fall Time (Note 9)	tf		23		ns	7		

Notes:

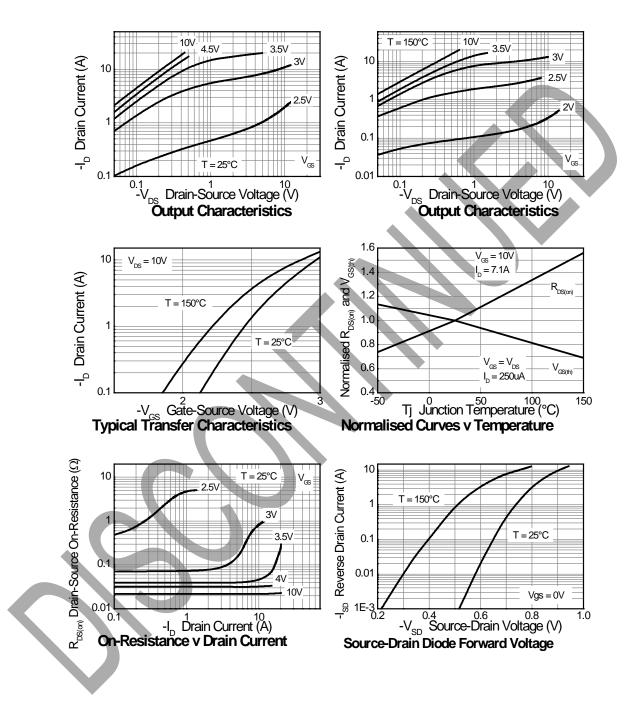
- Measured under pulsed conditions. Pulse width ≤ 300µs; duty cycle ≤ 2%
  For design aid only, not subject to production testing.
  Switching characteristics are independent of operating junction temperatures.



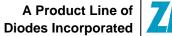




## **Typical Characteristics**

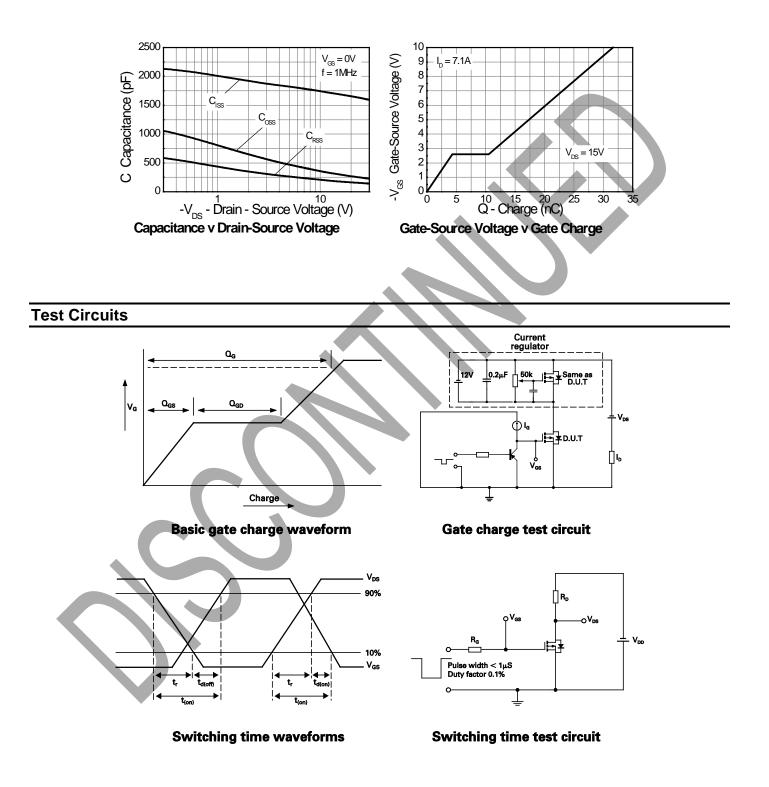






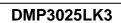


#### **Typical Characteristics - continued**

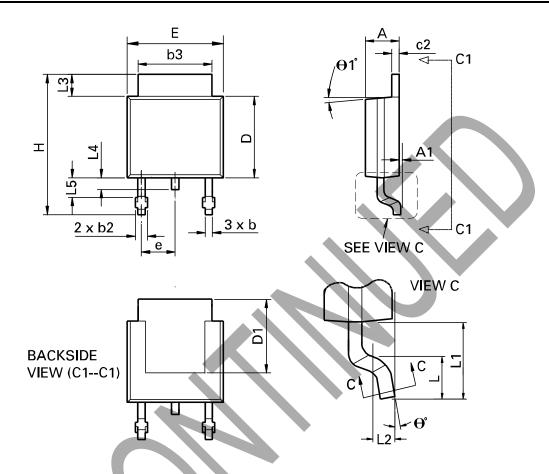






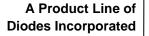


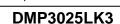
## Package Outline Dimensions



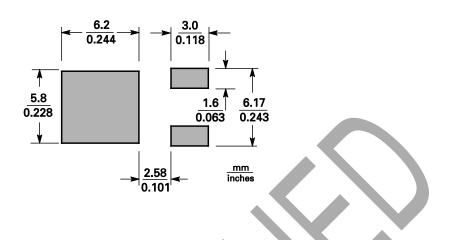
DIM	Inc	hes	Millimeters		DIM	Inches		Millimeters	
	Min	Max	Min	Max		Min	Max	Min	Max
А	0.086	0.094	2.18	2.39	е	0.090 BSC		2.29 BSC	
A1	-	0.005	-	0.127	Н	0.370	0.410	9.40	10.41
b	0.020	0.035	0.508	0.89	L	0.055	0.070	1.40	1.78
b2	0.030	0.045	0.762	1.14	L1	0.108 REF		2.74 REF	
b3	0.205	0.215	5.21	5.46	L2	0.020 BSC		0.508 BSC	
с	0.018	0.024	0.457	0.61	L3	0.035	0.065	0.89	1.65
c2	0.018	0.023	0.457	0.584	L4	0.025	0.040	0.635	1.016
D	0.213	0.245	5.41	6.22	L5	0.045	0.060	1.14	1.52
D1	0.205	-	5.21	-	•1°	0°	10°	0°	10°
Е	0.250	0.265	6.35	6.73	• °	0°	15°	0°	15°
E1	0.170	-	4.32	-	-	-	-	-	_







#### **Suggested Pad Layout**



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